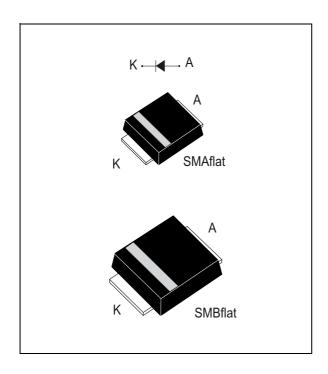


Power Schottky rectifier

Datasheet - production data



Description

The STPS3170 is a 170 V Schottky rectifier suited for switch mode power supplies and high frequency DC to DC converters.

Packaged in SMAflat and SMBflat, this device is especially intended for use in low voltage, high frequency inverters, freewheeling and polarity protection. Also ideal for all LED lighting applications where efficiency and space constraint are required.

Table 1. Device summary

Symbol	Value
I _{F(AV)}	3 A
V_{RRM}	170 V
V _F (typ)	0.63 V
T _j (max)	175 °C

Features

- · Negligible switching losses
- · High junction temperature capability
- Very small conduction losses
- Low leakage current
- Avalanche rated
- ECOPACK® compliant component
- T_i = -40 °C minimum operating

Characteristics STPS3170

1 Characteristics

Table 2. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage		170	V
V_{RRM}	Repetitive peak reverse voltage, T _j = -40 °C		160	V
I _{F(RMS)}	Forward rms current		15	Α
I _{F(AV)} Avera	A	SMAflat, T _L = 130 °C	2	
	Average forward current, δ = 0.5, square wave	SMBflat, T _L = 140 °C	3	A
	Surge non repetitive forward current, t _p = 10 ms	SMAflat	75	۸
I _{FSM}	sinusoidal	SMBflat	80	Α
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power, square wave	210	W	
T _{stg}	Storage temperature range	-65 to +175	°C	
T _j	Operating junction temperature ⁽²⁾	-40 to +175	°C	

For pulse time duration deratings, please refer to Figure 11. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the STMicroelectronics Application notes AN1768, "Admissible avalanche power of Schottky diodes" and AN2025, "Converter improvement using Schottky rectifier avalanche specification".

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
D	Junction to lead, SMAflat	20	°C/W
R _{th(j-l)}	Junction to lead, SMBflat	15	C/VV

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Povorco lookago current	T _j = 25 °C	V - V			4.0	μΑ
'R`´	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C	$V_R = V_{RRM}$		0.73	4.0	mA
	(2)	T _j = 25 °C	I _F = 3 A			0.82	
V _E ⁽²⁾		T _j = 125 °C			0.63	0.67	V
V _F ⁽²⁾ Forward voltage drop	T _j = 25 °C	I _F = 6 A			0.89	V	
		T _j = 125 °C	IF		0.70	0.75	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.59 \text{ x } I_{F(AV)} + 0.027 \text{ x } I_{F}^{2}_{(RMS)}$$

^{2.} $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

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Figure 1. Average forward power dissipation versus average forward current

2.5 $P_{F(AV)}(W)$ 2.6 $\delta = 0.05$ $\delta = 0.1$ $\delta = 0.2$ $\delta = 0.5$ $\delta = 1$ 2.0 $\delta = 0.5$ $\delta = 1$ 2.0 $\delta = 0.5$ $\delta = 1$ 3.1 $\delta = 0.2$ $\delta = 0.5$ $\delta = 1$ 4.0 $\delta = 0.5$ $\delta = 1$ 5.1 $\delta = 0.5$ $\delta = 1$ 6.1 $\delta = 0.5$ $\delta = 1$ 7.1 $\delta = 0.5$ $\delta = 1$ 8.2 $\delta = 0.5$ $\delta = 1$ 9.3 $\delta = 0.5$ $\delta = 1$ 9.4 $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.5 $\delta = 0.5$ $\delta = 1$ 9.6 $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.7 $\delta = 0.5$ $\delta = 1$ 9.8 $\delta = 0.5$ $\delta = 0.5$ $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.9 $\delta = 0.5$ $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.9 $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.9 $\delta = 0.5$ $\delta = 0.5$ $\delta = 0.5$ $\delta = 0.5$ $\delta = 1$ 9.9 $\delta = 0.5$ $\delta =$

Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)

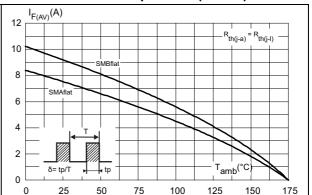


Figure 3. Relative variation of thermal impedance junction to lead versus pulse duration

 $Z_{\text{th(j-l)}}/R_{\text{th(j-l)}}$ 0.9 SMAflat 0.8 0.7 0.6 0.5 0.4 0.3 0.2 t_P(s) 0.0 1.E-04 1.E-03 1.E-02 1.E-01 1.E+00 1.E+01

Figure 4. Relative variation of thermal impedance junction to lead versus pulse duration

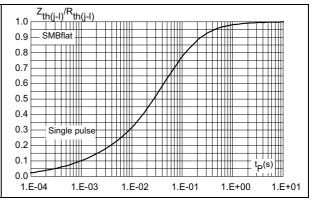


Figure 5. Reverse leakage current versus reverse voltage applied (typical values)

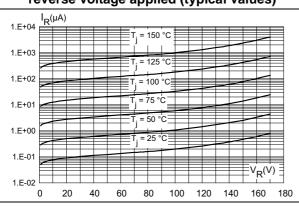
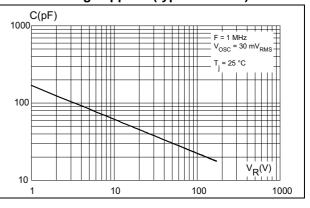


Figure 6. Junction capacitance versus reverse voltage applied (typical values)



Characteristics STPS3170

Figure 7. Forward voltage drop versus forward Figure 8. Forward voltage drop versus forward current (typical values) current (maximum values)

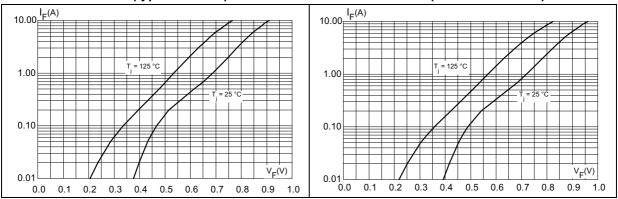


Figure 9. Thermal resistance junction to ambient versus copper surface under each lead ambient versus copper surface under each lead (typical values)

Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (typical values)

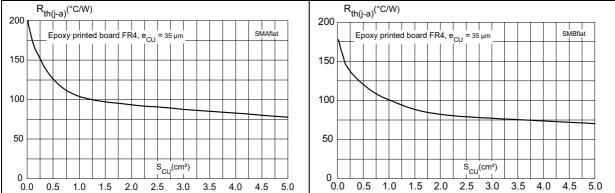
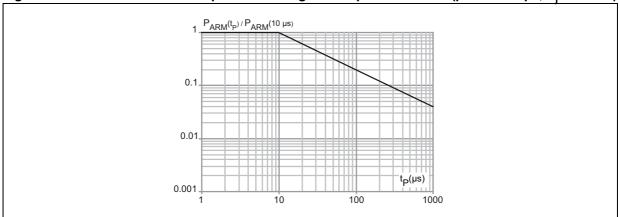


Figure 11. Normalized avalanche power derating versus pulse duration (pulse > 10 μ s, T_i < 150 °C)



STPS3170 Package information

2 Package information

- Epoxy meets UL94,V0
- Lead-free package
- · Band indicates cathode

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

E E1

L2x

L2x

L2x

L12x

Figure 12. SMAflat dimensions definitions

Package information STPS3170

Table 5. SMAflat dimension values

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.10	0.035		0.043
b	1.25		1.65	0.049		0.065
С	0.15		0.40	0.006		0.016
D	2.25		2.95	0.088		0.116
Е	4.80		5.60	0.189		0.220
E1	3.95		4.60	0.156		0.181
L	0.75		1.50	0.030		0.059
L1		0.50			0.019	
L2		0.50			0.019	

Figure 13. SMAflat footprint, dimensions in mm (inches)

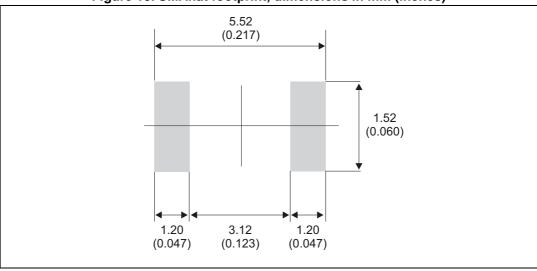
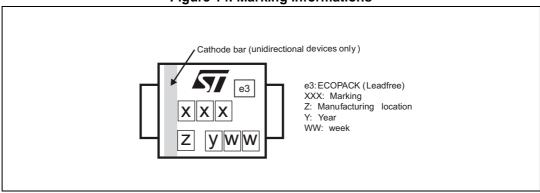


Figure 14. Marking informations



STPS3170 Package information

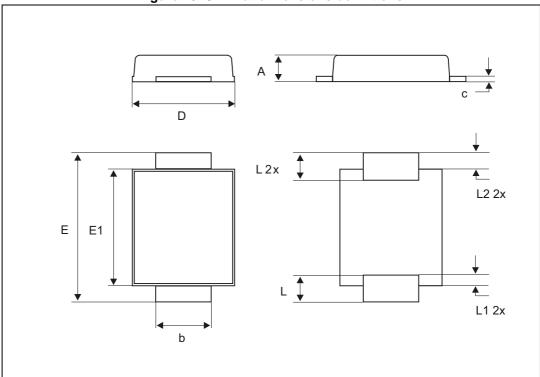


Figure 15. SMBflat dimensions definitions

Table 6. SMBflat dimension values

	Dimensions					
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	0.90		1.10	0.035		0.043
b	1.95		2.20	0.077		0.087
С	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.155
E	5.10		5.60	0.200		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.029		0.059
L1		0.40			0.016	
L2		0.60			0.024	

Package information STPS3170

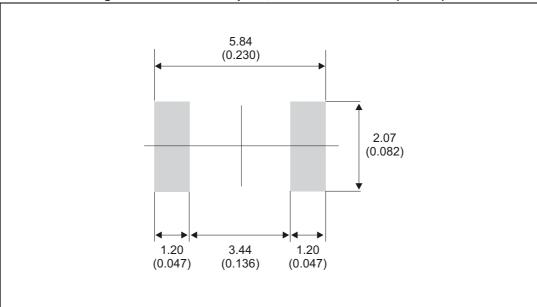


Figure 16. SMBflat footprint, dimensions in mm (inches)

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3170AF	F317	SMAflat	0.035 g	10000	Tape and reel
STPS3170UF	FG317	SMBflat	0.050 g	5000	Tape and reel

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
17-Oct-2014	1	First release.

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